

Notice of References Cited

Application/Control No.
09/833,372

Applicant(s)/Patent Under Reexam
Wojtowicz

Examiner
B. William Baumeister

Art Unit
2815

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* A copy of this reference is not being furnished with this Office action. See MPEP § 707.05(a).

¹ Dates in MM-YYYY format are publication dates.

² Classifications may be U.S. or foreign.